

Everything You Always Wanted To Know About Particle Detectors

The ATLAS Detector

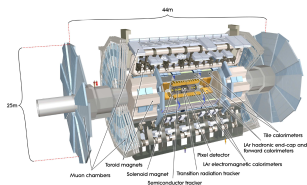
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Outline

- 1 Introduction
- 2 Particle & Photon Interaction Processes
- 3 ATLAS – Inner Detector
- 4 ATLAS – Calorimeter
- 5 ATLAS – Muon System
- 6 Summary

What Can Particle Detectors Measure?

hit

- presence

position

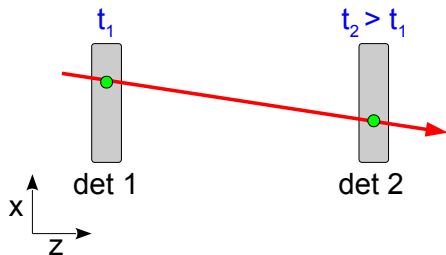
- tracking

timing

- trigger
- direction
- time-of-flight
→ velocity $\beta = \frac{\Delta z}{c\Delta t}$

energy loss \Leftrightarrow pulse height

- particle identification
- particle energy $\beta\gamma$



Underlying Mechanisms of Particle Detection?

some kind of interaction of particle in detector!

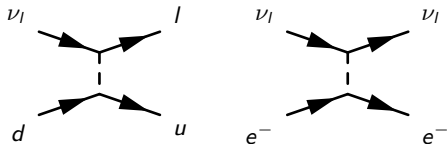
gravitation

- dark matter detection @ galactic dimension

→ irrelevant in HEP

weak force

- ν : charged & neutral current interactions



→ irrelevant in accelerator HEP

strong force

- hadrons & mesons
- dominant for neutrals
- calorimeters

electromagnetic force

- dominant for charged
- tracking, triggering, timing, calorimeters

Particle & Photon Interaction Processes

Electromagnetic Interaction of Particles With Matter

- excitation \rightarrow light
- ionization \rightarrow charge
- polarization (Cherenkov radiation) \rightarrow light
- transition radiation \rightarrow X-rays (\rightarrow charge)
- bremsstrahlung \rightarrow gammas (\rightarrow charge)

charge detectors

- gaseous, liquid, solid
- often finely segmented
- tracking, triggering
- integrated particle counting (calorimeters)

light detectors

- transparent medium
- scintillation detectors: detect light from deexcitation & recombination
- Cherenkov detectors
- triggering
- integrated particle counting (calorimeters)

note: photons produce charged particles via photo effect, Compton effect and pair production

Photon Interaction With Matter

photo effect

- $E_\gamma < 100 \text{ keV}$
- $E_{e^-} = E_\gamma - E_b$
→ sharp energy deposit
→ detector calibration
- $\sigma_{\text{photo}} \propto Z^5$

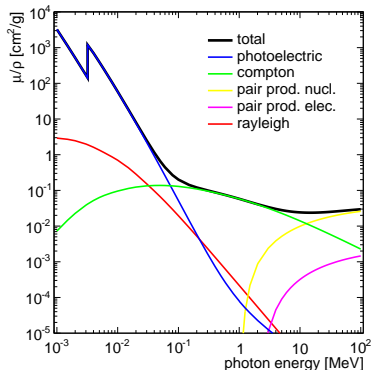
Compton effect

- $100 \text{ keV} < E_\gamma < 5 \text{ MeV}$
- $E'_\gamma = \frac{E_\gamma}{1 + (1 - \cos \vartheta) E_\gamma / m_e c^2}$

pair production

- $E_\gamma > 5 \text{ MeV}$
- $\sigma \propto \frac{\mu}{\rho} = \frac{7}{9} \frac{1}{X_0} \approx \text{const}(E_\gamma)$
 X_0 : radiation length
→ $P_{\text{pair}} = 1 - \exp(-7/9) \sim 54\%$
for $x = X_0$

$$I(x) = I_0 \exp(-\mu d) = I_0 \exp\left(-\frac{\mu}{\rho} x\right)$$



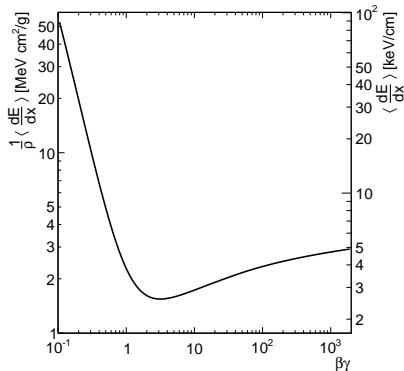
Bethe-Bloch-Formula

$$\left\langle \frac{dE}{dx} \right\rangle = -4\pi r_e^2 m_e c^2 \rho N_A \frac{Zz^2}{A\beta^2} \left(\frac{1}{2} \ln \frac{2m_e c^2 \beta^2 \gamma^2 T_{\max}}{I^2} - \beta^2 - \frac{\delta}{2} - \frac{C}{Z} \right)$$

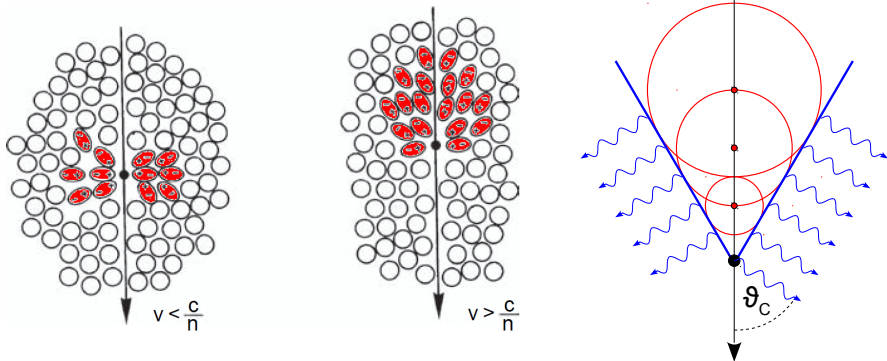
- includes ionization, excitation & polarization
- *mean* energy loss per unit length
- Photo Absorption Ionization model: Allison & Cobb, Ann. Rev. Nucl. Sci. 30 (1980) 253

characteristics

- universal function of $\beta\gamma$
→ particle ID: $p = \beta\gamma mc$
- $\left\langle \frac{dE}{dx} \right\rangle \propto \frac{1}{\beta^2}$ for $\beta\gamma < 1$
- $\left\langle \frac{dE}{dx} \right\rangle$ minimal for $\beta\gamma \sim 4$
- $\left\langle \frac{dE}{dx} \right\rangle \propto \ln \beta^2 \gamma^2$ for $10 < \beta\gamma < 500$
- $\left\langle \frac{dE}{dx} \right\rangle \sim \text{const.}$ for $\beta\gamma > 500$
- universal: $\frac{1}{\rho} \left\langle \frac{dE}{dx} \right\rangle = 2 \text{ MeV cm}^2/\text{g}$

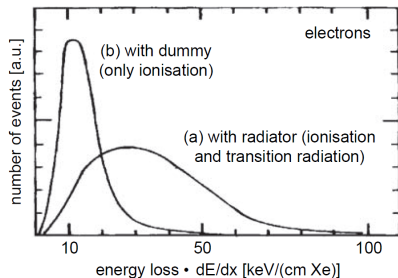
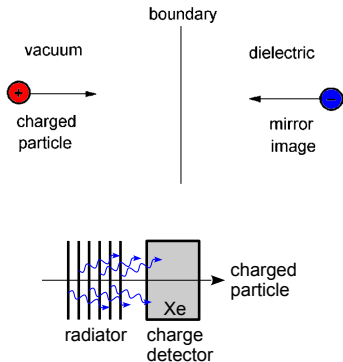


Cherenkov Radiation



- charged particle in material \rightarrow polarization
- $\beta > \frac{1}{n}$ = velocity of light in material
 - \rightarrow E-fields cannot follow
 - \rightarrow in-phase superposition of fields
 - \rightarrow emission of blueish light
 - \rightarrow optic analogon to sonic boom
- $\cos \vartheta_C = \frac{1}{\beta n}$
- $\frac{dN}{dx} = 490 \sin^2 \vartheta_C \text{ cm}^{-1}$

Transition Radiation



- charged particle at vacuum (gas)/solid boundary forms variable dipole with its mirror charge
→ emission of radiation (X-rays)
- radiated energy per boundary: $S = \frac{1}{3}\alpha z^2 \hbar \omega \gamma \propto \gamma$
- increase photon number
→ many layers
→ detect photons in high- Z gas detector together with Bethe-Bloch ΔE
- interference effects lead to saturation for $\gamma \sim 1000$

Bremsstrahlung

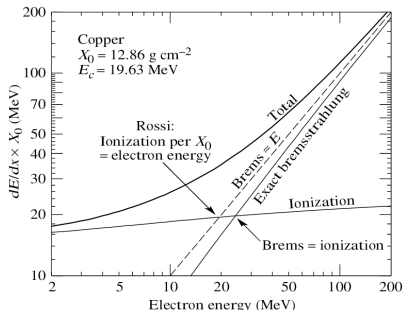
$$\frac{dE}{dx} = -4\alpha N_A \frac{Z^2}{A} z^2 \left(\frac{1}{4\pi\epsilon_0} \frac{e^2}{mc^2} \right)^2 \ln \frac{183}{Z^{1/3}} E$$

deceleration in coulomb field (nucleus,
weaker also shell electron)

→ emission of gammas

characteristics

- $\frac{dE}{dx} \propto \frac{1}{m^2}$
→ mostly relevant for electrons
- $\frac{dE}{dx} \propto E$
- $E^e(x) = E_0 \exp\left(-\frac{x}{X_0}\right)$,
 $X_0 = 4\alpha N_A \frac{Z^2}{A} z^2 r_e^2 \ln \frac{183}{Z^{1/3}}$: radiation length
- $\left. \frac{dE}{dx} \right|_{\text{bethe-bloch}} = \left. \frac{dE}{dx} \right|_{\text{brems}}$
at critical energy E_c
- $E_{c,\text{Fe}}^e \sim 21 \text{ MeV}$ & $E_{c,\text{Fe}}^\mu \sim 890 \text{ GeV}$



How To Measure Energy Loss?

ionization yield in charge detectors

- $n_e = \frac{\Delta E}{W_I}$
 W_I : mean energy per creation of one electron-ion pair ($> E_{\text{ionization}}!$)
- $W_{I,\text{Ar}} = 26 \text{ eV}$
- $W_{I,\text{Si}} \sim 4 \text{ eV}$

→ gas detectors: $\sim 100 \text{ e}^-/\text{cm}$
 → amplification in detector necessary

→ semiconductor detectors:
 $\sim 22000 \text{ e}^-/300 \mu\text{m}$
 → direct measurement

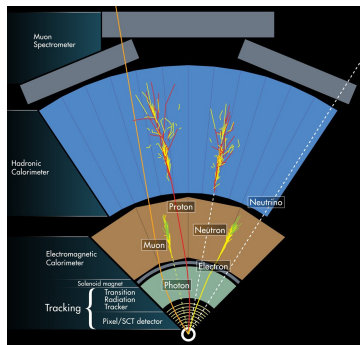
light yield in scintillation detectors

- $n_\gamma = \frac{\Delta E}{W_\gamma}$
 W_γ : mean energy per creation of one photon
- $W_\gamma \sim 100 \text{ eV}$

→ detect few to several ten thousand photons (possible)

What Info Are We Interested In?

- presence
- timing
- position

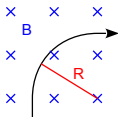


identity

- specific interactions
- $\frac{dE}{dx}$ measurement + p
- charge: from p
- via mass:
 $E^2 - p^2c^2 = m^2c^4$
(difficult)

momentum

- $p = \beta\gamma mc$
- magnetic field:
 $p = qRB$



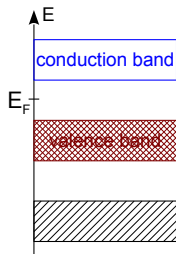
energy

- $E = \gamma mc^2$
- identity + p
- range measurement
- measure complete energy deposition

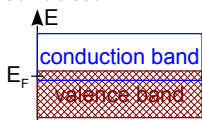
ATLAS – Inner Detector

Reminder: Band Model & Semiconductors

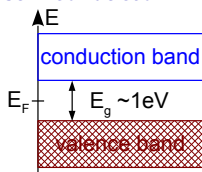
- Schrödinger equation for electron energy in periodic lattice
→ quasi-continuous energy bands
- valence band: fully occupied @ $T = 0\text{ K}$, e^- bound to atoms
- conduction band: empty @ $T = 0\text{ K}$, e^- could move within lattice



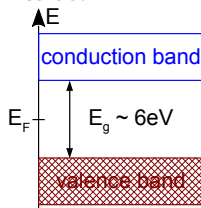
conductor



semiconductor

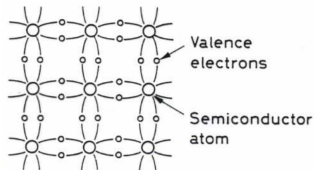


insulator



Conductivity of Semiconductors

$T = 0\text{ K}$

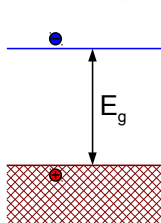


- valence band completely occupied
- conduction band empty

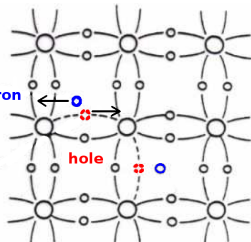
→ $\sigma = 0$

→ insulating

$T > 0\text{ K} + E\text{-field}$



free
electron

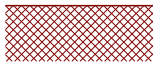
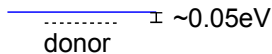
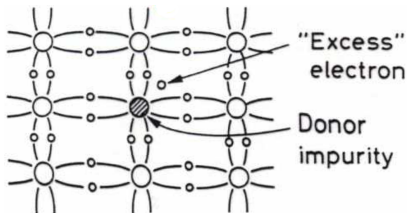


- $\sigma = e(n_n\mu_n + n_p\mu_p)$
→ electrons (n) & holes (p) contribute to conductivity
- $n_n = n_p \sim 5 \times 10^{15} T^{3/2} \exp(-\frac{E_g}{2kT})$
- strong temperature dependence
- 300 K: $\rho_{\text{Si}} = 1/\sigma_{\text{Si}} \sim 10^5 \Omega\text{cm}$
→ low conductivity
→ strong dependence on impurities

Doping of Semiconductors $\rightarrow \rho \sim 10^3 \Omega\text{cm}$

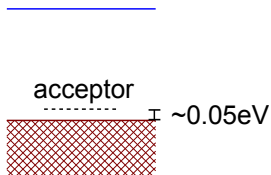
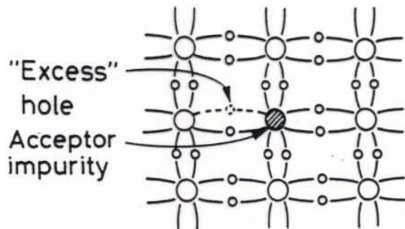
n-type

- add quinquevalent impurity (e.g. P)

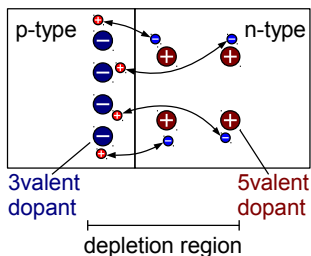


p-type

- add trivalent impurity (e.g. B)



P-N Junction



- electrons diffuse into p-type
- holes diffuse into n-type

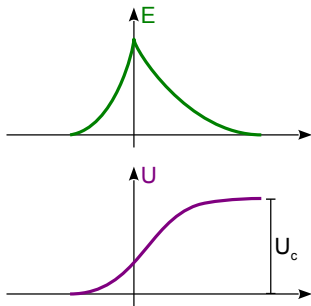
→ recombine

→ dopant trunks produce space charge

→ space charge prevents further diffusion

formation of depletion region: no free charge carriers

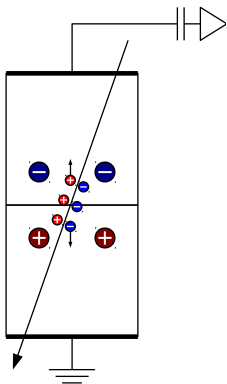
→ no current in reverse bias direction (diode behavior)



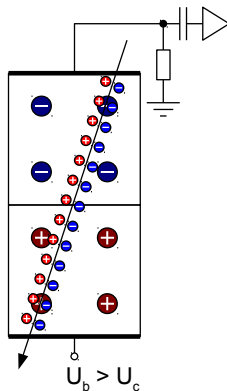
in reality: leakage current due to thermal excitation of semiconductor or contaminants and defects

→ strong reduction by cooling

P-N Junction as Particle Detector



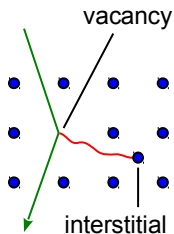
- charged particle
→ **ionization** & excitation
- charge separation only in depletion region
→ current pulse



- reverse bias voltage $U_b \sim 100\text{ V}$
→ increase depletion region
→ increase current pulse & active volume

Aging of Semiconductor Detectors

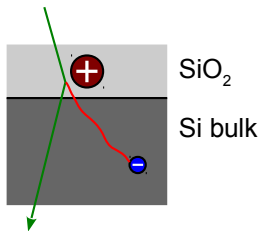
bulk damage



- higher leakage current
- capturing of e^- or holes
→ charge collection efficiency
- space charge
- type inversion: n-type bulk → p-type bulk
→ p-n junction at n^+ -bulk interface

→ adapt U_b accordingly

surface damage



- surface leakage current
- space charge

Annealing of Semiconductor Detectors

- empiric: damage \propto integrated dose Φ
- interstitials and vacancies diffuse within warm semiconductor

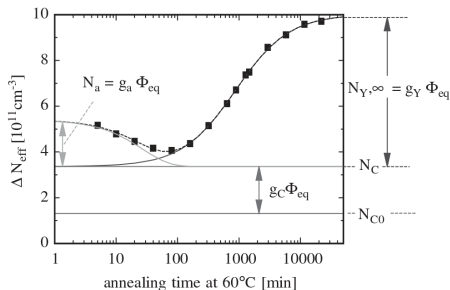
beneficial annealing

- recombination of single interstitials & vacancies
- short term

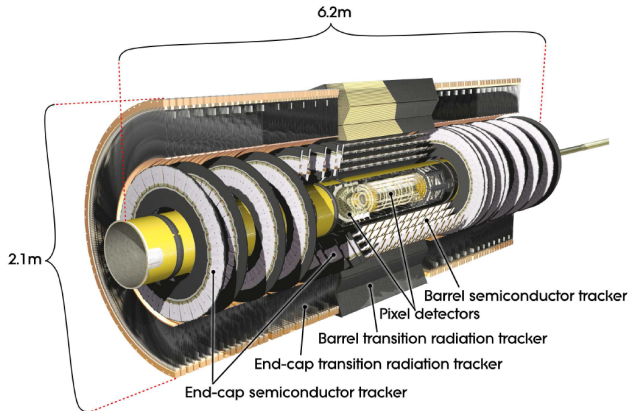
reverse annealing

- undesired
- long term

stable damage

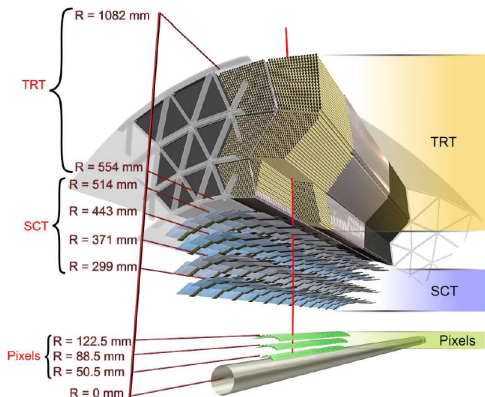


Inner Detector



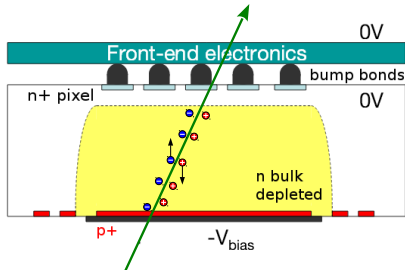
- momentum measurement with high resolution
→ whole ID in 2 T solenoidal B -field
- primary & secondary vertex reconstruction
- pattern recognition
- electron identification
- high spatial resolution
- high granularity
- transition radiation detector

Inner Detector Components

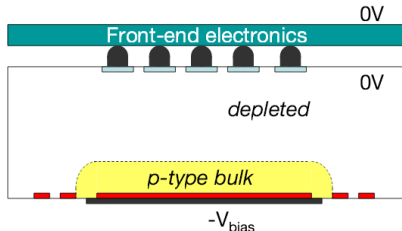


- transition radiation tracker
 - many layers 4 mm straw tubes
→ at least 36 individual position measurement points
 - embedded in TR radiator (polypropylene fibres (barrel) and foils (endcap)) → especially electrons produce TR X-rays, 7 to 10 detected TR photons with much higher pulse height per traversing electron
- four double-layers silicon microstrip detectors ($\sim 80\mu\text{m} \times 12$ cm)
- four layers silicon pixel detectors
 - insertable B-layer: $50\mu\text{m} \times 250\mu\text{m}$ (planar and 3D pixels, not treated in this talk)
 - three outer layers: $50\mu\text{m} \times 400\mu\text{m}$

Silicon Pixel Modules



before irradiation:
p-n junction between
p+ and n-type bulk

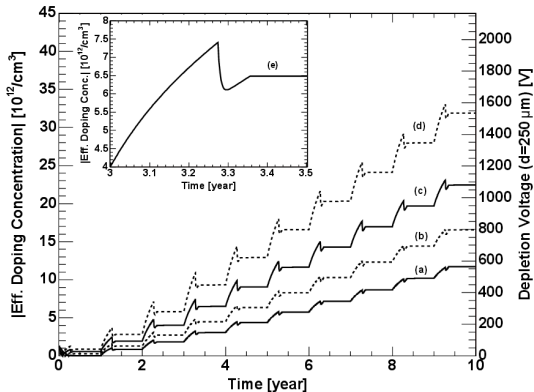


after irradiation & type inversion:
p-n junction between p-type bulk
and n+ pixels

- 250 μm thick n-type bulk
- readout electronic directly bonded onto sensor
- 50 μm \times 400 μm pixel size
→ spatial resolution 10 μm & 115 μm
- type inversion & ageing anticipated
→ n⁺ pixels
→ U_b from 150 V to 600 V
- cooled to -10° idle, 0° in operation

Aging of Pixel Modules

- aging: increase of effective dopant concentration
- increase bias voltage to reach full depletion
- 100 days operation @ 0°
- 30 days maintenance @ 20°
→ annealing
- rest: idle @ -10°
- $U_b = 600$ V maximum!



a:

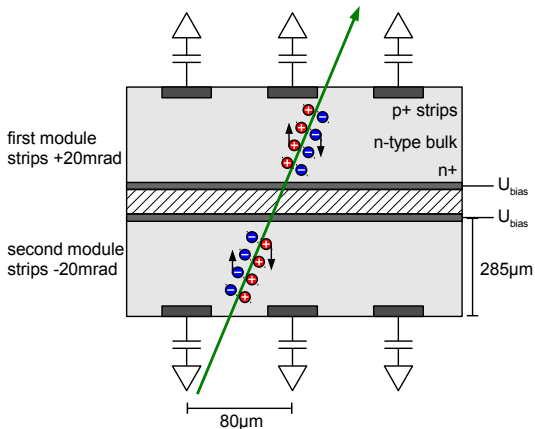
$R = 88$ mm layer for nominal dose

c: $R = 50$ mm layer for nominal dose

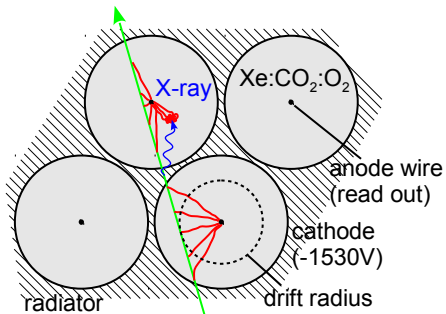
b & d: same as a and c but for 1.5 nominal dose

Silicon Microstrip Modules

- two layers per module, stereo angle 40 mrad
- conventional p-in-n-type: large area & cost
- readout electronic wire bonded to sensor
- spatial resolution $17\ \mu\text{m}$ & $580\ \mu\text{m}$ (from stereo angles)
- type inversion & ageing anticipated
→ U_b from 150 V to 500 V, sufficiently large margin
- cooled to -7° for reduced leakage current and reverse annealing



Transition Radiation Tracker



- radial E -field in straw tube
→ strong close to wire
- ionization along particle track (100 e)
- charge amplification around wire (25k)
- measure earliest arrival time
- $t_{\text{drift}} = \frac{r_{\text{drift}}}{v(r_{\text{drift}})}$
→ drift radius
↔ position $O(130 \mu\text{m})$
- TR: $E_{\gamma} \sim 20 \text{ keV} \rightarrow 900 \text{ e}$
- Why Xe ($Z = 54$, extremely expensive)? remember: $\sigma_{\text{photo}} \propto Z^5$

ATLAS – Calorimeter

Measurement Principle: Electromagnetic Sampling Calorimeter

dominant interaction of

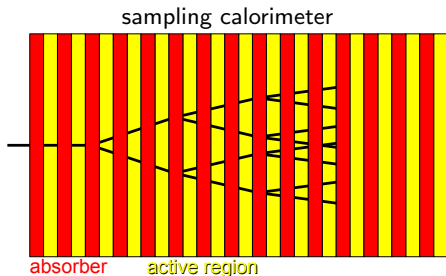
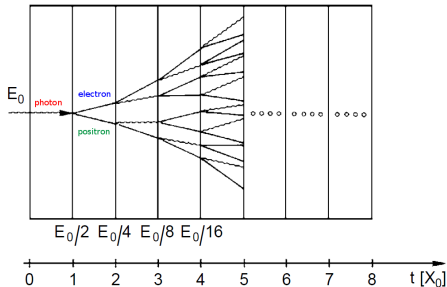
- high energy electrons: bremsstrahlung
→ photons
- high energy photons: pair production

remember: after $1X_0$:

- $P_{\text{brems}} \sim 63\%$
- $P_{\text{pair}} = 1 - \exp(-7/9) \sim 54\%$

→ shower develops

- shower stops when $E(t) < E_c$
- number of e^\pm & γ : $N(t) \sim 2^t$
- mean particle energy:
 $E(t) \sim E_0/N(t) = E_0 2^{-t}$
- at maximum depth: $E(t) = E_c$
→ $E_0 2^{t_{\text{max}}} = E_c$
- total particle path \Leftrightarrow number of e^\pm :
 $S = \sum_{t=0}^{t_{\text{max}}} \frac{2}{3} N(t) \sim \frac{2}{3} 2^{t_{\text{max}+1}} = \frac{4}{3} \frac{E_0}{E_c}$
- note: for constant ionization: $S \propto Q$

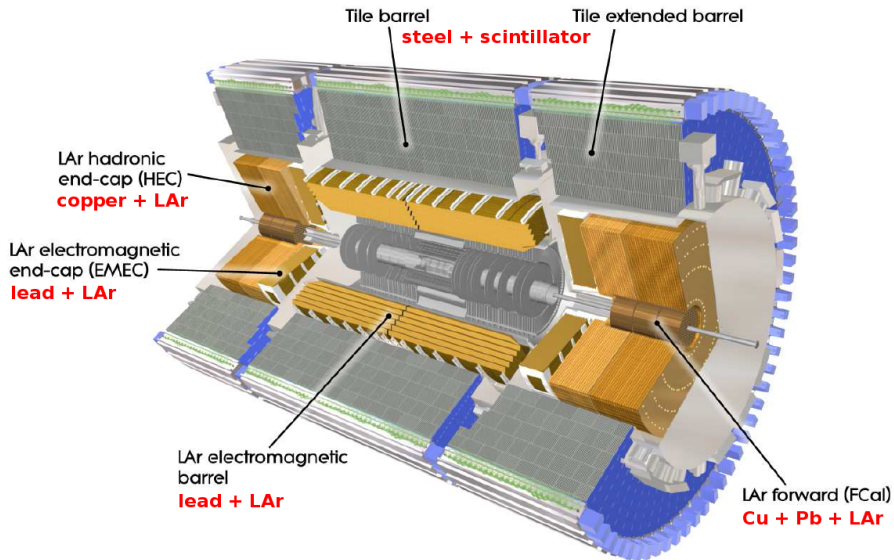


Hadronic Sampling Calorimeter

- equivalent to EM calo but hadronic interaction \leftrightarrow bremsstrahlung/pair production
- nuclear interaction length $\lambda \gg X_0$
 → much thicker absorber plates than in EM
- hadron cascades: more particles with difficult energy determination (ν & μ leave calo, $\pi^0 \rightarrow \gamma\gamma$ are lost in absorber, slow nuclear fragments ionize strongly)
 → energy resolution worse than in EM calo

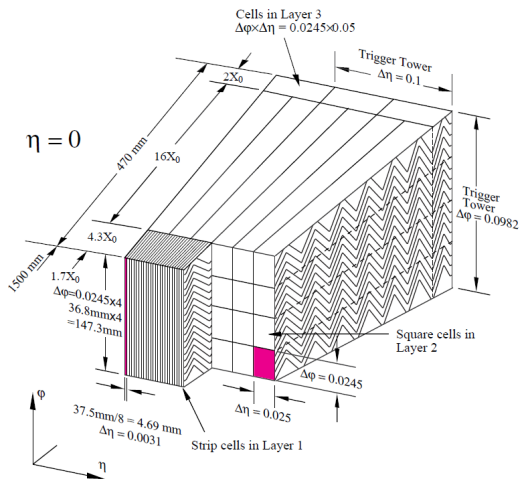
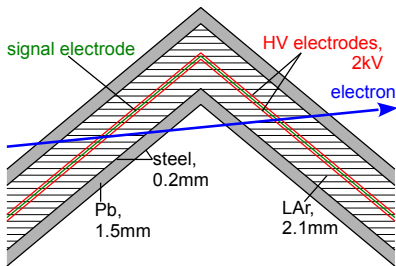
material	λ [cm]	X_0 [cm]
LAr	85.8	14.0
Fe	16.8	1.76
Cu	15.3	1.44
Pb	17.6	0.56
W	9.95	0.35

ATLAS Calorimeter System

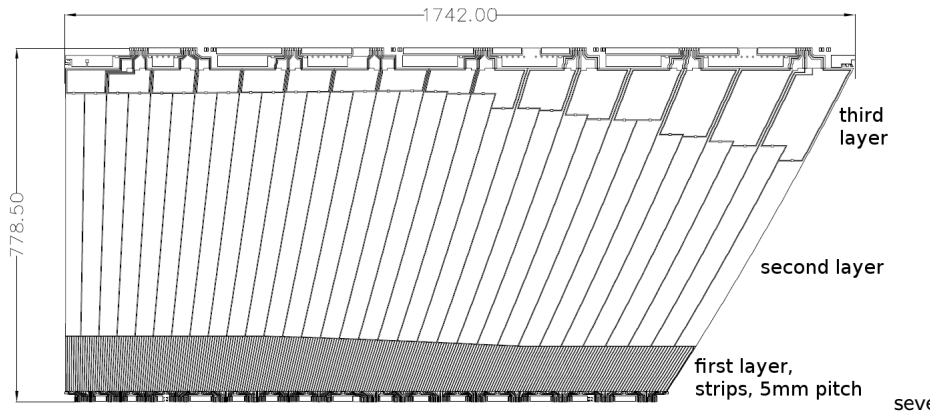


Electromagnetic Barrel Calorimeter

- absorber: lead (1.5 mm & 1.1 mm for $\eta > 0.8$) between 0.2 mm steel
- active layer: twice 2.1 mm LAr
- two HV electrodes for electron-ion-separation
- charge signal collected by electrode
- three layers in depth: segmentation of signal electrode



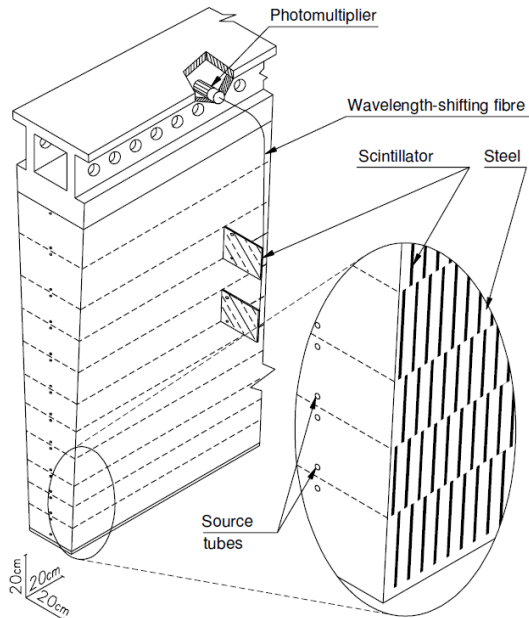
Electromagnetic Barrel Calorimeter – Signal Electrode



signal electrodes from adjacent LAr-gaps are grouped to form cells

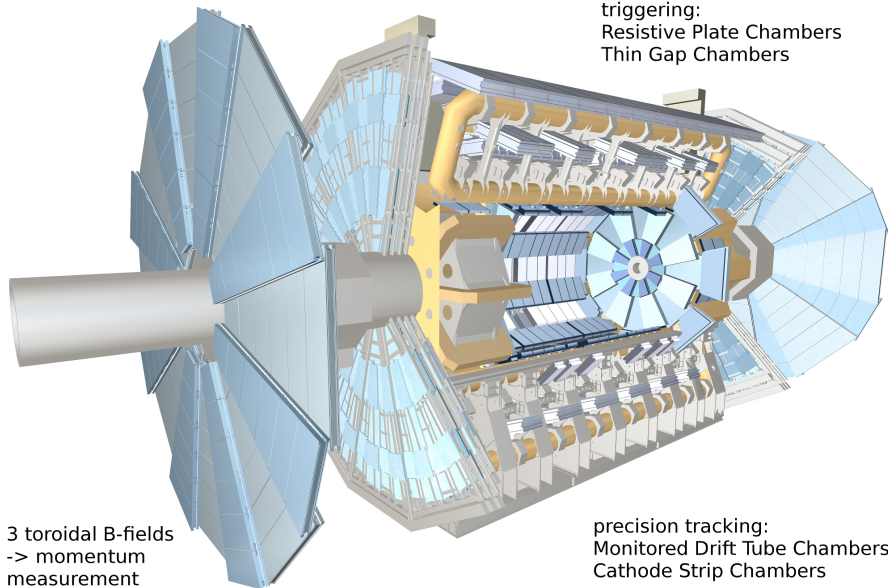
Hadronic Barrel Calorimeter

- absorber: steel
(5 mm × 97 mm × 200 mm to
5 mm × 187 mm × 400 mm)
- active layer: 3 mm plastic
scintillator tiles
- scintillation light from both
sides decoupled via
wavelength-shifting fibers
- fibers grouped & read out via
photomultiplier
- three layers in depth



ATLAS – Muon System

Quarter of the ATLAS Muon System

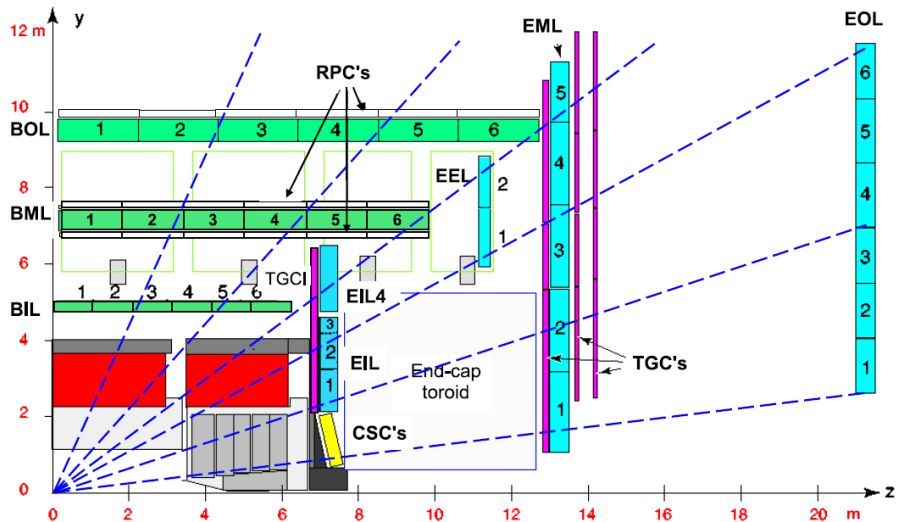


triggering:
Resistive Plate Chambers
Thin Gap Chambers

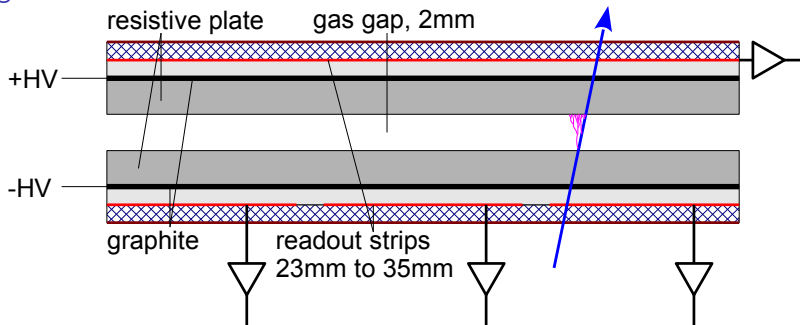
3 toroidal B-fields
-> momentum
measurement

precision tracking:
Monitored Drift Tube Chambers
Cathode Strip Chambers

ATLAS Muon System



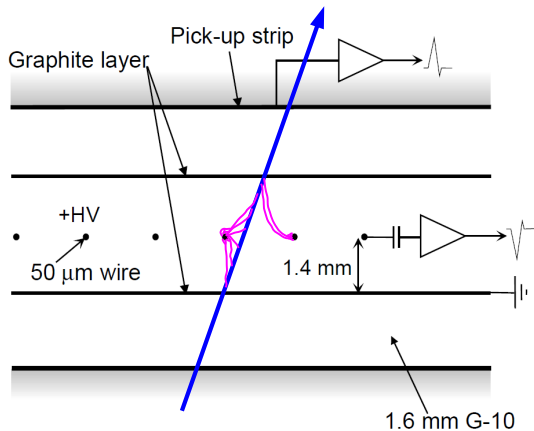
Trigger Barrel: Resistive Plate Chambers



- 2 mm gas gap, $C_2H_2F_4:iC_4H_{10}:SF_6$
- highly resistive plates, contacted by graphite layers
- charged particle \rightarrow ionization
- homogenous E -field (49 kV/cm) \rightarrow gas amplification & electron-ion separation
- fast signal on perpendicular readout strips (1.5 ns resolution, 5 ns duration)
- coarse position information $O(35\text{ mm})$ per module
- two modules per chamber

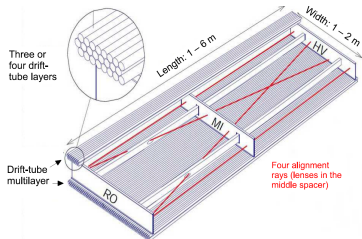
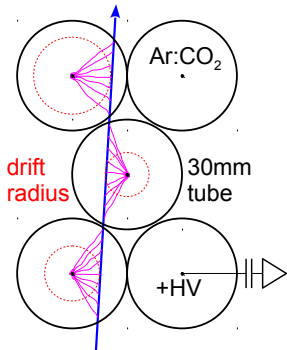
Trigger Endcap: Thin Gap Chambers

- 2.8 mm planar gas gap, $\text{CO}_2:\text{nC}_5\text{H}_{12}$
- 50 μm wires, pitch 1.8 mm, 2.9 kV
- charged particle \rightarrow ionization
- electrons drift to wires \rightarrow saturated gas amplification
- signal on wire
- signal on perpendicular readout strips
- spatial resolution $O(5 \text{ mm})$ per layer, timing resolution 4 ns



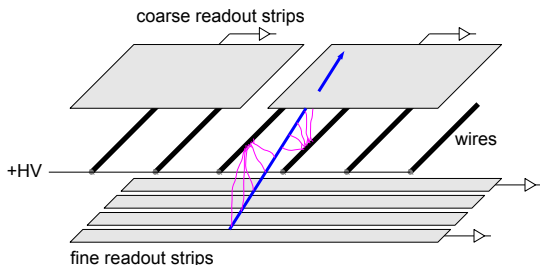
Tracking Barrel/Endcap: Monitored Drift Tube Chambers

- 30 mm aluminum tube, Ar:CO₂ 93:7, 3 bar
- central 50 μm wire, 3 kV
- charged particle \rightarrow ionization
- electrons drift to central wire (max 700 ns)
 \rightarrow gas amplification
- measure earliest arrival time of electrons
 \rightarrow drift radius
- combine 6 to 8 tube layers
 \rightarrow particle track $O(35 \mu\text{m})$
- $2 \times 5 \text{ m}^2$ max size \rightarrow deformation: temperature gradients, mounting position
 \rightarrow wire position has to be known with $O(30 \mu\text{m})$
 \rightarrow monitor relative position and internal deformation via optical system



Tracking Inner Endcap: Cathode Strip Chambers

- 5 mm planar gas gap, Ar:CO₂
- 30 μm wires, pitch 2.5 mm, 1.9 kV, not read out
- charged particle \rightarrow ionization
- electrons drift to wires \rightarrow gas amplification
- mirror signal on two layers of perpendicular readout strips
- precision coordinate: 1.85 mm pitch, every third read out \rightarrow spatial resolution $O(60 \mu\text{m})$ per layer
- coarse coordinate: 21 mm & 13 mm pitch \rightarrow spatial resolution $O(5\text{mm})$ per layer



Summary

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- charged particles & photons: EM interaction dominant
 - excitation
 - ionization
 - Cherenkov radiation
 - transition radiation
 - bremsstrahlung
 } Bethe-Bloch
- neutral hadrons: strong interaction
- charge detectors \leftrightarrow light detectors
- detectors: presence, timing, position
- momentum measurement (track radius in B -field), energy (range or calorimetric), identity
- ATLAS:
 - transition radiation tracker
 - electromagnetic lead-LAr calorimeter
 - hadronic steel-scintillator calorimeter
 - resistive plate chambers
 - thin gap chambers
 - monitored drift tube chambers
 - cathode strip chambers
 } muon trigger
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Thank you!